NSN 5961-01-459-8454

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View Online at https://aerobasegroup.com/nsn/5961-01-459-8454 **Inclosure Material:** Plastic **Overall Length:** 4.0 millimeters **Overall Height:** 2.6 millimeters **Overall Width:** 2.6 millimeters **End Application:** 6625-01-443-0552 e/i fscm 03950 Voltage Rating In Volts Per Characteristic: 35.0 collector to emitter voltage/static/base open and 6.0 emitter to collector voltage, dc **Current Rating Per Characteristic:** 20.00 milliamperes source cutoff current **Power Rating Per Characteristic:** 50.0 milliwatts small-signal input power, common-collector **Maximum Operating Tempurature Per Measurement Point:** 85.0 degrees celsius ambient air **Terminal Type And Quantity:** 2 ribbon Shelf Life: N/a **Unit Of Measure: Demilitarization:** No